

1200 V Gen 4 Power Silicon Carbide Schottky Diode, 10 A



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I _F 10 A						
V _R	1200 V					
V _F at I _F at 25 °C, typ.	1.34 V					
T _J max.	175 °C					
I _R at V _R at 175 °C	162 µA					
Q _C (V _R = 800 V)	52 nC					
Package	TO-220AC 2L					
Circuit configuration	Single					

FEATURES

Positive V_F temperature coefficient for easy paralleling



• Virtually no recovery tail and no switching losses

Temperature invariant switching behavior

COMPLIANT HALOGEN FREE

- 175 °C maximum operating junction temperature
- Solder bath temperature 275 °C maximum, 10 s per JESD 22-B106
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Wide band gap SiC based 1200 V Schottky diode, designed for high performance and ruggedness.

Optimized for extreme high-speed hard switching across a wide temperature range. This SiC diode is ideal for demanding applications such as high efficiency PFC diodes and ultra-high frequency output rectifiers in AC/DC and DC/DC converters.

MECHANICAL DATA

Case: TO-220AC 2L

Molding compound meets UL 94 V-0 flammability rating Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

Mounting torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage	V_{RRM}		1200	V			
Continuous forward current	I _F ⁽¹⁾	T _C = 155 °C (DC)	10	Α			
Continuous forward current	I _F ⁽²⁾	T _C = 145 °C (DC)	10	Α			
DC blocking voltage	V_{DC}		1200	V			
Repetitive peak forward current	I _{FRM}	$T_C = 25$ °C, f = 50 Hz, square wave, DC = 25 %	44	_			
Non-venetitive peak forward average average	I _{FSM}	$T_C = 25$ °C, $t_p = 10$ ms, half sine wave	50	A			
Non-repetitive peak forward surge current		$T_C = 110 ^{\circ}\text{C}$, $t_p = 10 \text{ms}$, half sine wave	45	Α			
	P _{tot} (1)	T _C = 25 °C	136	— w — w			
Danier diagination		T _C = 110 °C	59				
Power dissipation	P _{tot} (2)	T _C = 25 °C	94				
		T _C = 110 °C	41				
I ² t value	∫i ² dt	T _C = 25 °C	12.5	A ² s			
		T _C = 110 °C	10.3				
Operating junction and storage temperatures	T _J ⁽³⁾ , T _{Stg}		-55 to +175	°C			

Notes

- (1) Based on typical R_{th}
- (2) Based on maximum Rth
- $^{(3)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$



ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS	
		I _F = 10 A	-	1.34	1.6		
Forward voltage	V _F	I _F = 10 A, T _J = 150 °C	-	1.7	2.1	V	
		I _F = 10 A, T _J = 175 °C	-	1.85	-		
	I _R	$V_R = V_R$ rated	-	5.4	80	μΑ	
Reverse leakage current		V _R = V _R rated, T _J = 150 °C	-	72	500		
		V _R = V _R rated, T _J = 175 °C	-	162	-		
Total capacitance	С	V _R = 1 V, f = 1 MHz	-	590	-	nE	
		V _R = 800 V, f = 1 MHz	-	36	-	pF	
Total capacitive charge	Q _C	V _R = 800 V, f = 1 MHz	-	52	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS (T _A = 25 °C unless otherwise specified)							
PARAMETER SYMBOL TEST CONDITIONS MIN. TYP. MAX. UNITS							
Thermal resistance, junction to case	R _{thJC}		-	1.1	1.6	°C/W	
Marking device	ice 4C10ET12T						

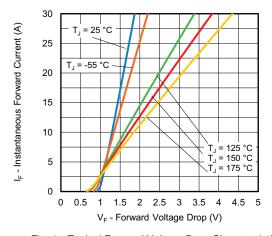


Fig. 1 - Typical Forward Voltage Drop Characteristics

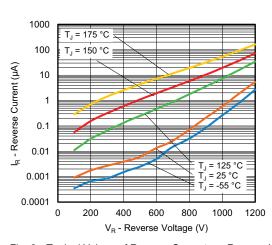


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

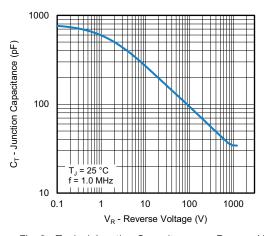


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

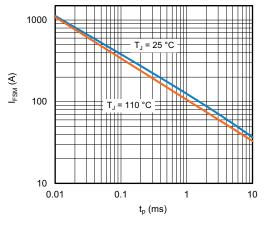


Fig. 4 - Non-Repetitive Peak Forward Surge Current vs. Pulse Duration (Square Wave)

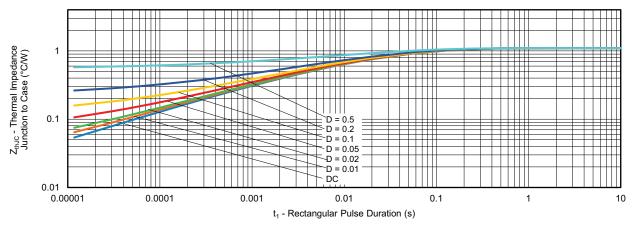


Fig. 5 - Typical Thermal Impedance Z_{thJC} Characteristics

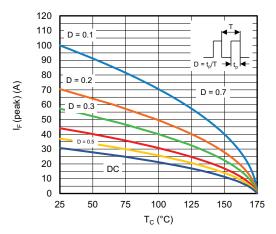


Fig. 6 - Peak Forward Current vs. Maximum Allowable Case Temperature

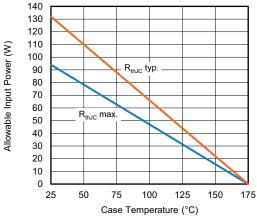


Fig. 7 - Forward Power Loss Characteristics

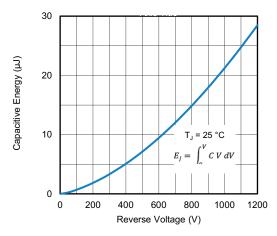


Fig. 8 - Typical Capacitive Energy vs. Reverse Voltage

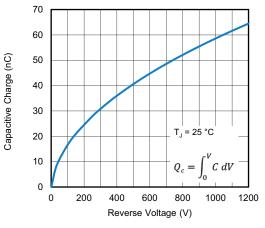
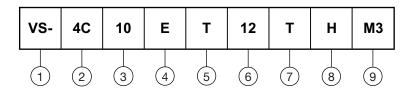


Fig. 9 - Typical Capacitive Charge vs. Reverse Voltage



ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - 4C = SiC diode, generation 4

Current rating (10 = 10 A)

- E = single diode

T = TO-220AC 2L

Voltage rating: (12 = 1200 V)

7 - T = true 2 pin

8 - H = AEC-Q101 qualified

9 - Environmental digit:

M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

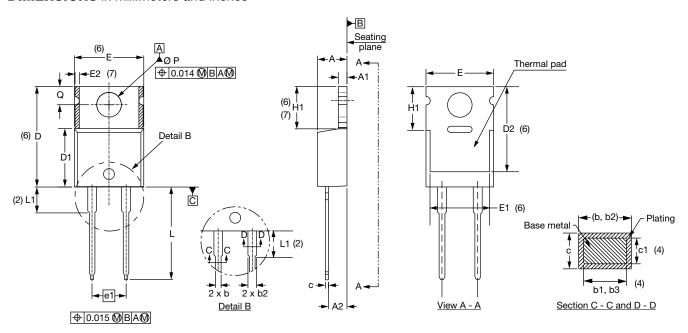
ORDERING INFORMATION						
PREFERRED P/N	UNIT WEIGHT	BASE QUANTITY	PACKAGING DESCRIPTION			
VS-4C10ET12THM3	2 g	50 per tube	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96069			
Part marking information	www.vishay.com/doc?95391			



TO-220AC 2L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	MILLIMETERS		INCHES		
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.25	4.65	0.167	0.183		
A1	1.14	1.40	0.045	0.055		
A2	2.56	2.92	0.101	0.115		
b	0.69	1.01	0.027	0.040		
b1	0.38	0.97	0.015	0.038	4	
b2	1.20	1.73	0.047	0.068		
b3	1.14	1.73	0.045	0.068	4	
С	0.36	0.61	0.014	0.024		
c1	0.36	0.56	0.014	0.022	4	
D	14.85	15.25	0.585	0.600	3	
D1	8.38	9.02	0.330	0.355		
D2	11.68	12.88	0.460	0.507	6	
Е	10.11	10.51	0.398	0.414	3, 6	

SYMBOL	MILLIMETERS		INC	NOTES	
STIMBUL	MIN.	MAX.	MIN.	MAX.	NOTES
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
e1	4.88	5.28	0.192	0.208	
H1	5.84	6.86	0.230	0.270	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- $^{(7)}$ Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC® TO-220, except D2, where JEDEC® minimum is 0.480"



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